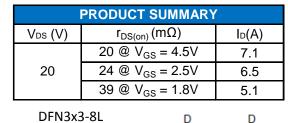
# N-Channel 20-V (D-S) MOSFET

### **Key Features:**

- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- · Fast switching speed

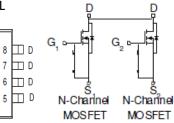
### **Typical Applications:**

- White LED boost converters
- · Automotive Systems
- Industrial DC/DC Conversion Circuits





Top View





ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)							
Parameter			Symbol	Limit	Units		
Drain-Source Voltage			V <sub>DS</sub>	20	V		
Gate-Source Voltage	e-Source Voltage		V <sub>GS</sub>	±8	V		
Continuous Drain Current <sup>a</sup>		=25°C	I	7.1	А		
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =	=70°C	I <sub>D</sub>	5.8			
Pulsed Drain Current <sup>b</sup>			I <sub>DM</sub>	40			
Continuous Source Current (Diode Conduction) <sup>a</sup>			ا <sub>s</sub>	2.1	А		
Dower Dissinction <sup>a</sup>		=25°C	P <sub>D</sub>	1.5	W		
Power Dissipation <sup>a</sup>	T <sub>A</sub> =	=70°C	U 'D	1	vv		
Operating Junction and Storage Temperature Range			T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C		

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
Maximum Junction-to-Ambient <sup>a</sup>	t <= 10 sec	R <sub>eja</sub>	83	°C/W		
	Steady State	٩٢٩	120	0/11		

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Parameter	arameter Symbol Test Conditions		Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	0.4			V	
Gate-Body Leakage		$V_{DS} = 0 V, V_{GS} = \pm 8 V$			±100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 16 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	uA	
	I <sub>DSS</sub>	$V_{DS} = 16 \text{ V},  V_{GS} = 0 \text{ V},  \text{T}_{\text{J}} = 55^{\circ}\text{C}$			25		
On-State Drain Current	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	10			А	
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 5.7 \text{ A}$			20	mΩ	
Drain-Source On-Resistance	r <sub>DS(on)</sub>	$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 5.2 \text{ A}$			24		
		$V_{GS} = 1.8 \text{ V}, \text{ I}_{D} = 4.8 \text{ A}$			39		
Forward Transconductance	<b>g</b> <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 5.7 \text{ A}$		15		S	
Diode Forward Voltage	V <sub>SD</sub>	$I_{S} = 1.1 \text{ A}, V_{GS} = 0 \text{ V}$		0.71		V	
Dynamic							
Total Gate Charge	Qg	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 4.5 V,		6			
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 10$ V, $V_{GS} = 4.3$ V, $I_{D} = 5.7$ A		0.9		nC	
Gate-Drain Charge	$Q_gd$	1 <u>0</u> = 3.7 A		2.5			
Turn-On Delay Time	t <sub>d(on)</sub>	V = 10 V R = 180		8			
Rise Time	t <sub>r</sub>	$I_{D} = 5.7 \text{ A}.$		14		ns	
Turn-Off Delay Time	t <sub>d(off)</sub>			42			
Fall Time	t <sub>f</sub>	$V_{\text{GEN}} = 4.5 \text{ V}$ ; $V_{\text{GEN}} = 0.32$		17			
Input Capacitance	C <sub>iss</sub>			439			
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ = 15 V, $V_{GS}$ = 0 V, f = 1 MHz		78		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			68			

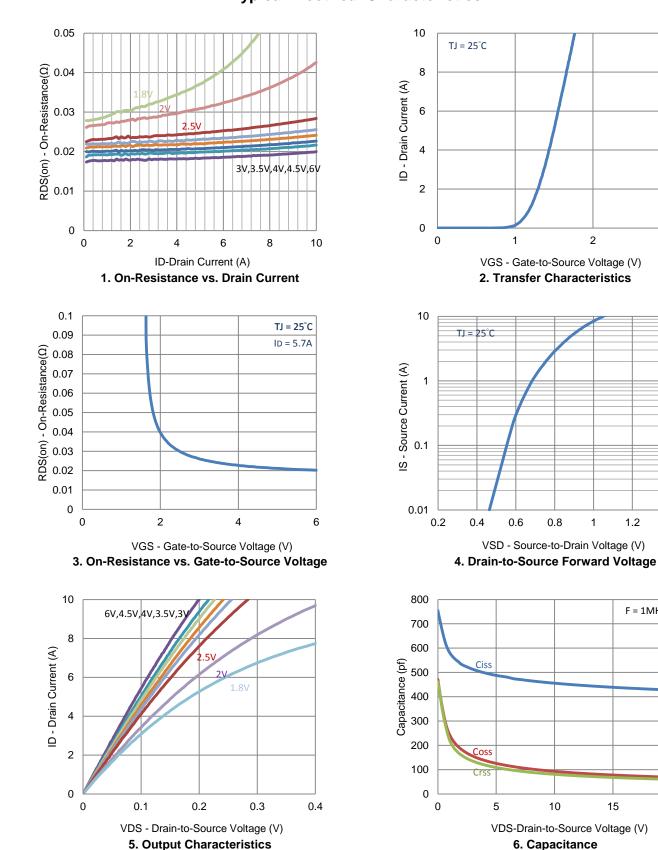
## **Electrical Characteristics**

#### Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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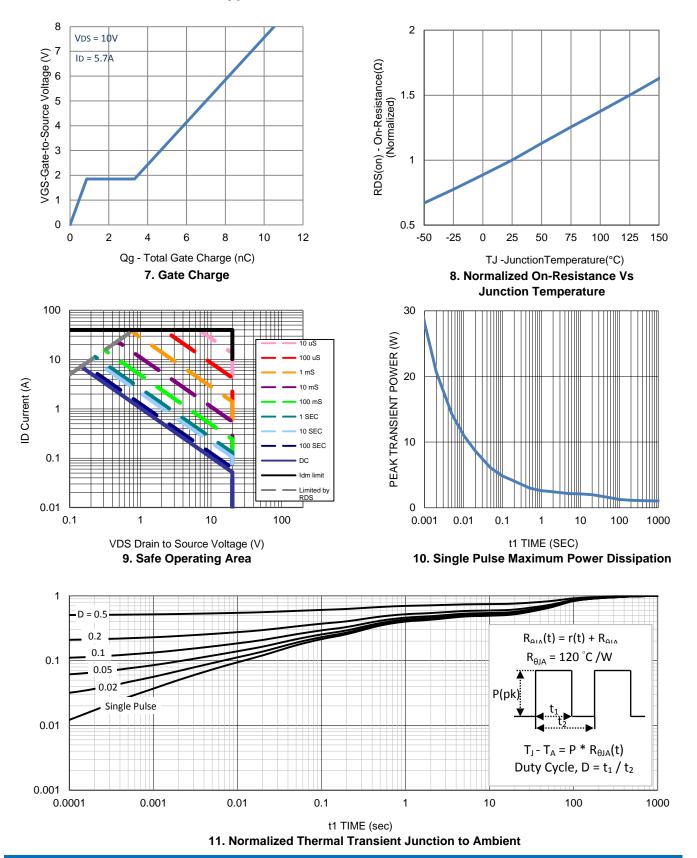
## **Typical Electrical Characteristics**

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1.2

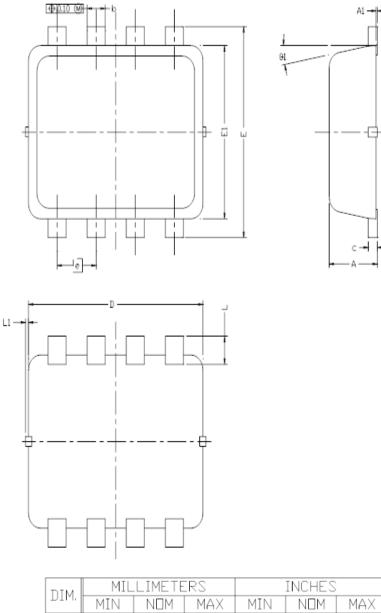
F = 1MHz

1.4



## **Typical Electrical Characteristics**

## Package Information



DIM.		MIL	LIMETE	-K2	INCHES			
	DIM	MIN	NDM	MAX	MIN	NDM	MAX	
	Α	0,700	0,80	0.900	0.0276	0.0315	0.0354	
	A1	0,00		0.05	0,000		0.002	
	b	0,24	0,30	0,35	0.009	0.012	0,014	
	$\subset$	0,08	0.152	0.25	0.003	0,006	0.010	
	D	2	2.90 BS	С	0.114 BSC			
	E	2	2.80 BS	С	0.110 BSC			
	E1	2	2.30 BS	С	0.091 BSC			
	e	0.65 BSC			0.026 BSC			
	L	0,20	0.375	0.450	0.008	0.0148	0.0177	
	L1	Û		0.100	Û		0.004	
	01	0	10	12	0	10	12	